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High Performance Schottky Rectifier, 1.0 A



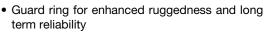


SMB (DO-214AA)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1 A			
V _R	90 V, 100 V			
V _F at I _F	0.78 V			
I _{RM}	1 mA at 125 °C			
T _J max.	175 °C			
E _{AS}	1.0 mJ			
Package	SMB (DO-214AA)			
Circuit configuration	Single			

FEATURES

- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation





- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-MBRS190-M3, VS-MBRS1100-M3 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	Α		
V _{RRM}		90, 100	V		
I _{FSM}	$t_p = 5 \mu s sine$	870	Α		
V _F	1.0 A _{pk} , T _J = 125 °C	0.63	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRS190-M3	VS-MBRS1100-M3	UNITS
Maximum DC reverse voltage	V_R	90	100	V
Maximum working peak reverse voltage	V_{RWM}	O	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 147 °C, rectangular waveform		1.0	
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	870	Α
	I _{FSM}	10 ms sine or 6 ms rect. pulse		50	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.5 \text{A}, L = 8 \text{mH}$		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 0.5		Α	



VS-MBRS190-M3, VS-MBRS1100-M3

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V (1)	1 A	T _J = 25 °C	0.78	V
See fig. 1	V _{FM} ⁽¹⁾	IA	T _J = 125 °C	0.62]
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _o = Rated V _o	0.5	- mA
See fig. 2	'RM \"	T _J = 125 °C		1.0	
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		42	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

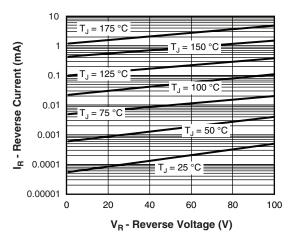
THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	C/VV
Approximate weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (DO-214AA)	19/	10

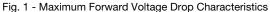
Notes

(1) dP_{tot} < 1/Pth square PCB

Ten square PCB

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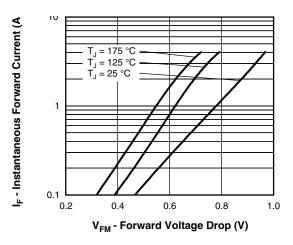


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

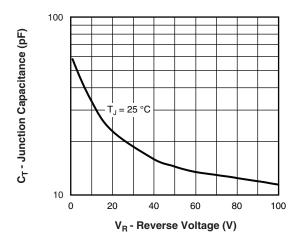


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

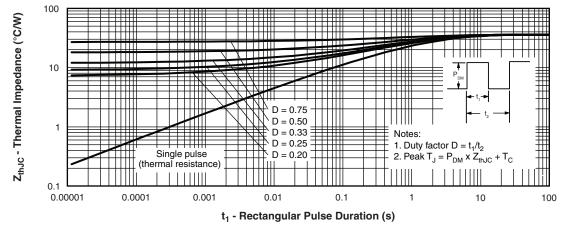


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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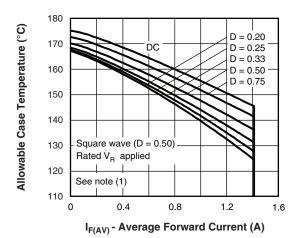


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

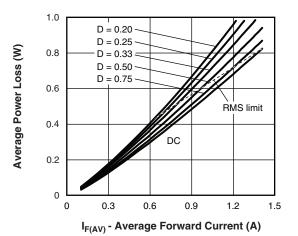


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

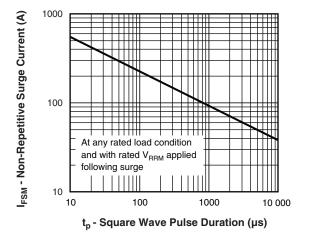


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

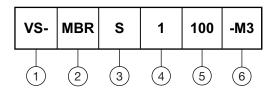
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-MBRS190-M3, VS-MBRS1100-M3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

S = SMB (DO-214AA)

Current rating (1 = 1 A)

90 = 90 V 100 = 100 V

6 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBRS190-M3/5BT	5BT	3200	13" diameter plastic tape and reel	
VS-MBRS1100-M3/5BT	5BT	3200	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95401		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		
SPICE model	www.vishay.com/doc?95516		
SPICE model	www.vishay.com/doc?96602		

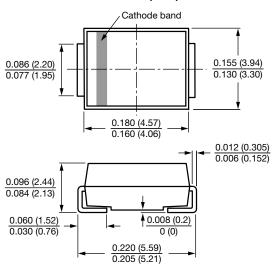


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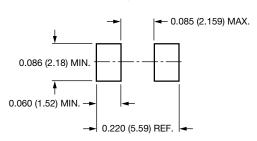
SMB

DIMENSIONS in inches (millimeters)

DO-214AA (SMB)



Mounting Pad Layout





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